

SANYO Semiconductors DATA SHEET

SFT1403—General-Purpose Switching Device Applications

Features

- · Motor drive application.
- · Low ON-resistance.
- · 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		35	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		14	Α
Drain Current (PW≤10μs)	IDP	PW≤10μs, duty cycle≤1%	56	Α
Allowable Power Dissipation	D-		1.0	W
	PD	Tc=25°C	20	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Llois
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	35			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =35V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =7A	6.6	11		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=7A, VGS=10V		17	23	mΩ
	R _{DS} (on)2	I _D =7A, V _G S=4V		25	35	mΩ

Marking: T1403 Continued on next page.

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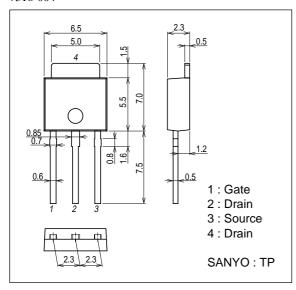
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Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Onit
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		2230		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		305		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		225		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		21		ns
Rise Time	t _r	See specified Test Circuit.		110		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		140		ns
Fall Time	tf	See specified Test Circuit.		100		ns
Total Gate Charge	Qg	V _{DS} =20V, V _{GS} =10V, I _D =14A		39		nC
Gate-to-Source Charge	Qgs	V _{DS} =20V, V _{GS} =10V, I _D =14A		7.7		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =20V, V _{GS} =10V, I _D =14A		7.2		nC
Diode Forward Voltage	V _{SD}	I _S =14A, V _{GS} =0V		0.92	1.2	V

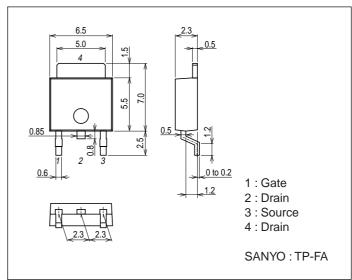
Package Dimensions

unit : mm (typ) 7518-004

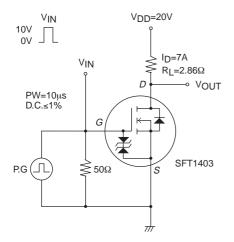


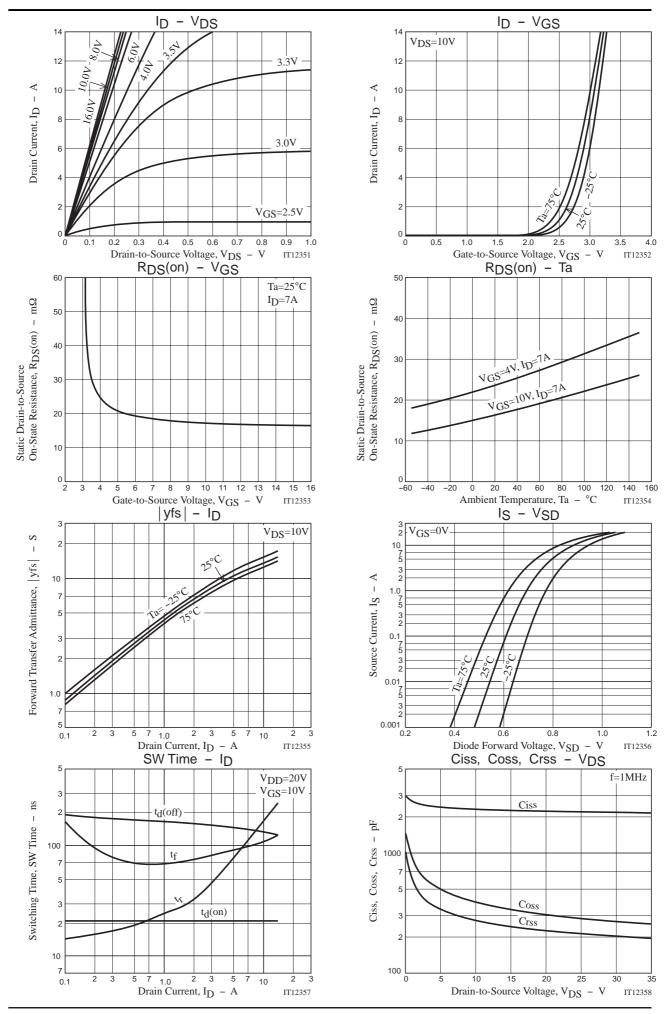
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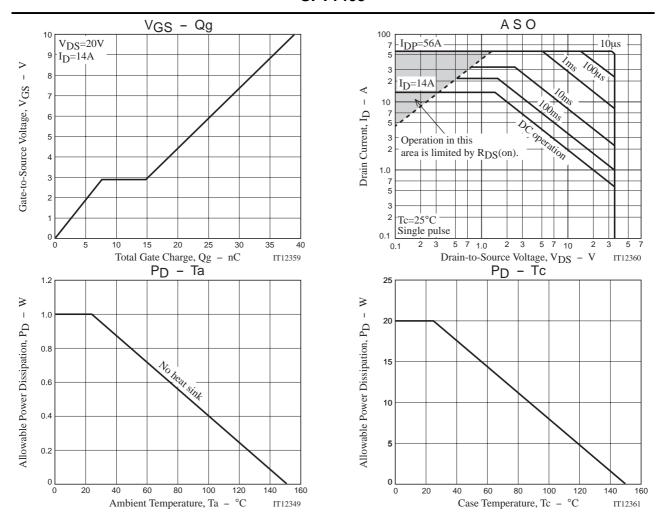
unit : mm(typ) 7003-004



Switching Time Test Circuit







Note on usage: Since the SFT1403 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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